



### 30V P-Channel Enhancement Mode MOSFET

Voltage

-30 V

Current

-4.6 A

#### **Features**

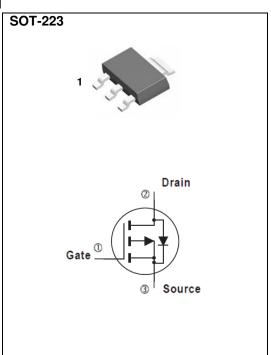
- $R_{DS(ON)}$ ,  $V_{GS}$ @-10V,  $I_D$ @-3A<50m $\Omega$
- $R_{DS(ON)}$ ,  $V_{GS}$ @-4.5V,  $I_{D}$ @-2A<80m $\Omega$
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

#### **Mechanical Data**

• Case: SOT-223 Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• SOT-223 Approx. Weight: 0.043 ounces, 0.123grams



### **Maximum Ratings and Thermal Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V <sub>DS</sub>	-30	V	
Gate-Source Voltage		$V_{GS}$	<u>+</u> 20		
Continuous Drain Current	T <sub>A</sub> =25°C		-4.6		
	T <sub>A</sub> =70°C	I <sub>D</sub>	-3.7	Α	
Pulsed Drain Current (Note 1)		I <sub>DM</sub>	-20		
Power Dissipation	T <sub>A</sub> =25°C	P <sub>D</sub>	1.6	10/	
	T <sub>A</sub> =70°C		1.0	W	
Operating Junction and Storage Temperature Range		$T_J, T_{STG}$	-55~150	°C	
Typical Thermal Resistance - Junction to Ambient (Note 5)		$R_{ heta JA}$	78.1	°C/W	

• Limited only By Maximum Junction Temperature

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### **Electrical Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =-250uA	-30	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=-250uA$	-1	-1.6	-2.5	
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	$V_{GS}$ =-10V, $I_D$ =-3A	-	40	50	mΩ
		$V_{GS}$ =-4.5V, $I_{D}$ =-2A	-	60	80	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS}$ =-30V, $V_{GS}$ =0V	-	-	-1	uA
Gate-Source Leakage Current	I <sub>GSS</sub>	$V_{GS} = \pm 20V, V_{DS} = 0V$	-	-	<u>+</u> 100	nA
Dynamic (Note 6)						
Total Gate Charge	Qg	$V_{DS}$ =-15V, $I_{D}$ =-3A, $V_{GS}$ =-4.5V (Note 1,2)	-	4.8	-	nC
Gate-Source Charge	Q <sub>gs</sub>		-	1.7	-	
Gate-Drain Charge	$Q_{gd}$		-	1.7	-	
Input Capacitance	Ciss	V <sub>DS</sub> =-15V, V <sub>GS</sub> =0V, f=1.0MHZ	-	516	-	pF
Output Capacitance	Coss		-	83	-	
Reverse Transfer Capacitance	Crss	I=1.0IVIDZ	-	61	-	
Turn-On Delay Time	td <sub>(on)</sub>		-	5.6	-	ns
Turn-On Rise Time	t <sub>r</sub>	$V_{DS}$ =-15V, $I_{D}$ =-1A, $V_{GEN}$ =-10V, $R_{G}$ =6 $\Omega$ (Note 1,2)	-	8.5	-	
Turn-Off Delay Time	td <sub>(off)</sub>		-	27	-	
Turn-Off Fall Time	t <sub>f</sub>		-	18	-	
Drain-Source Diode						
Maximum Continuous Drain-Source	,		-	-	-4.6	А
Diode Forward Current	I <sub>S</sub>					
Diode Forward Voltage	$V_{SD}$	I <sub>S</sub> =-1A, V <sub>GS</sub> =0V	-	-0.76	-1	V

#### NOTES:

- 1. Pulse width < 300us, Duty cycle < 2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. The maximum current rating is package limited.
- 4. Repetitive rating, pulse width limited by junction temperature  $T_{J(MAX)}$ =150°C. Ratings are based on low frequency and duty cycles to keep initial  $T_J$  =25°C.
- 5. R@JA is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch<sup>2</sup> with 2oz.square pad of copper.
- 6. Guaranteed by design, not subject to production testing.





#### **TYPICAL CHARACTERISTIC CURVES**

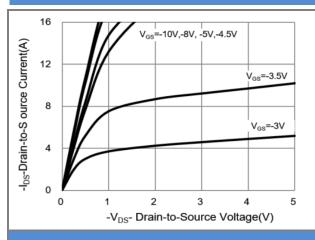
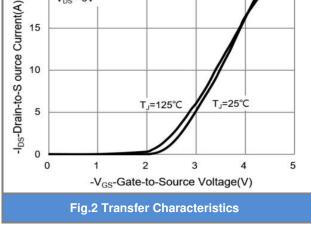


Fig.1 Output Characteristics



V<sub>DS</sub>=-5V

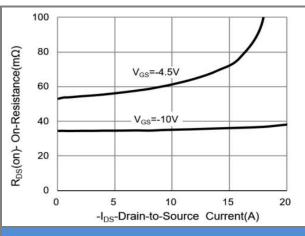


Fig.3 On-Resistance vs. Drain Current

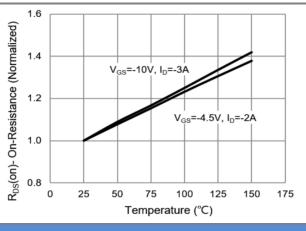
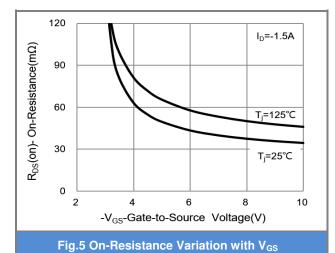


Fig.4 On-Resistance vs. Junction temperature



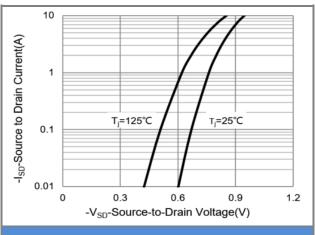


Fig.6 Source-Drain Diode Forward Voltage

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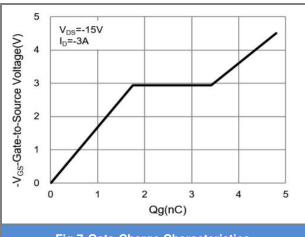


Fig.7 Gate-Charge Characteristics

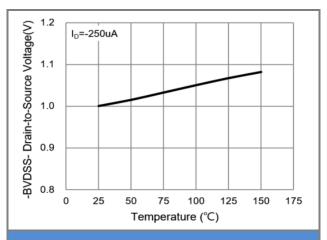


Fig.8 Breakdown Voltage Variation vs. Temperature

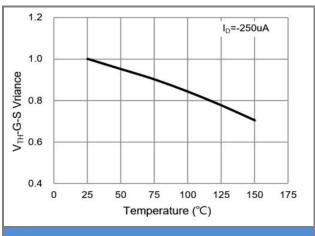


Fig.9 Threshold Voltage Variation with Temperature

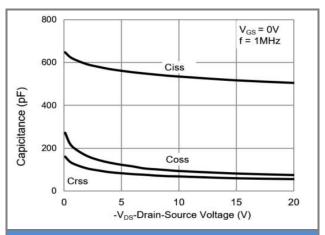
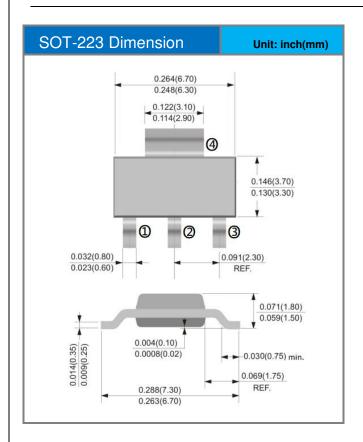


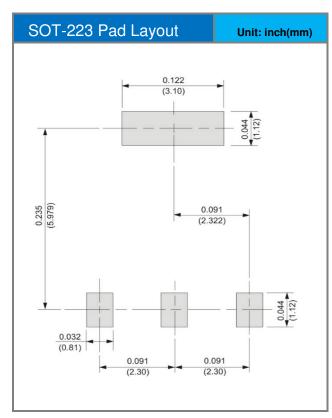
Fig.10 Capacitance vs. Drain-Source Voltage





### **Packaging Information & Mounting Pad Layout**









### **Part No Packing Code Version**

Part No Packing Code	Package Type	Packing Type	Marking	Version	
PJW5P03_R2_00001	SOT-223	2,500pcs / 13" reel	W5P03	Halogen free	

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